**JUNE 1990** PRODUCT BULLETIN

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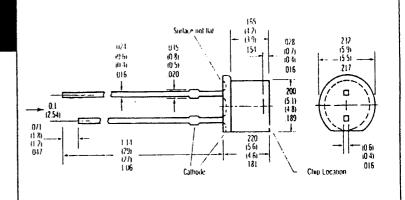
fibre-d<u>ata</u>

FIBRE OPTIC. 850nm PiN DIODE

## TYPE: FDR 850 IR

## FEATURES

- **ULTRA-LOW COST**
- HI REL EPOXY PACKAGE
- VERY FAST RESPONSE TIME
- HIGH RESPONSIVITY



DESCRIPTION This device provides users with outstanding performance and high reliability at extremely low cost. It is the most cost effective P.i.N diode to have been produced for 1st window fibre optic applications.

## MAXIMUM RECOMMENDED RATINGS (TA = 25° C Unless otherwise noted)

Reverse Voltage ...... 30 V

Storage Temperature Range ...... -55 °C to +100 °C

Operating Temperature Range ...... -55 °C to +100 °C

Power Dissipation ...... 100 mW

## OPTO/ELECTRICAL CHARACTERISTICS

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PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
RESPONSIVITY			0.62		A/W	@ 850 nM
DARK CURRENT	Id		1.0	10	пA	$V_R = 20 \text{ V (NOTE 2)}$
PEAK RESPONSE WAVELENGTH			850		nМ	NOTE 1
CAPACITANCE			3.8		pf	$V_R = 5 V$ (NOTE 2) f = 1 MHz
OUTPUT RISE TIME	t r		2		nS	$R_L = 50 \Omega$ (NOTE 3) $V_R = 5 V$
OUTPUT FALL TIME	t f		2		nS	$R_L = 50 \Omega$ (NOTE 3) $V_R = 5 V$
FREQUENCY CHARACTERISTICS	:1		500		MHz	Cutoff Frequency

**NOTES:** 

- 1. Response range 10% to 10% is 375 1100 nM
- 2. Not Illuminated
- 3. Measured at 850 nM,  $I_p = 14 \mu A$